TOSHIBA THYRISTOR SILICON PLANAR TYPE

S6744

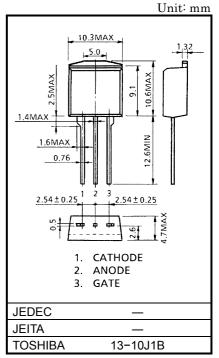
MEDIUM POWER CONTROL APPLICATIONS

• Repetitive Peak Off-State Voltage : $V_{DRM} = 400V$ Repetitive Peak Reverse Voltage : $V_{RRM} = 400V$ • Average On-State Current : $I_{T}(AV) = 8A$

• A Large Current Pulse Capability

MAXIMUM RATINGS

CHARACTERISTIC	SYMBOL	RATING	UNIT	
Repetitive Peak Off-State Voltage and Repetitive Peak Reverse Voltage	$V_{ m DRM}$ $V_{ m RRM}$	400	V	
Non-Repetitive Peak Reverse Voltage (Non-Repetitive<5ms, $T_j = 0 \sim 125$ °C)	V_{RSM}	500	V	
Average On-State Current (Half Sine Waveform Tc = 72°C)	I _{T (AV)}	8	Α	
R.M.S On-State Current	I _{T (RMS)}	12.6	Α	
Peak One Cycle Surge On-State Current (Non-Repetitive)	I _{TSM}	200 (50Hz)	А	
		220 (60Hz)		
I ² t Limit Value	I ² t	200	A ² s	
Repetitive Peak Surge On-State Current (Note 1)	I _{TRM}	1300	Α	
Critical Rate of Rise of On-State Current (Note 2)	di / dt	100	A / μs	
Peak Gate Power Dissipation	P _{GM}	5	W	
Average Gate Power Dissipation	P _G (AV)	0.5	W	
Peak Forward Gate Voltage	V_{FGM}	10	V	
Peak Reverse Gate Voltage	V _{RGM}	-5	٧	
Peak Forward Gate Current	I _{GM}	2	Α	
Junction Temperature	Tj	-40~125	°C	
Storage Temperature Range	T _{stg}	-40~125	°C	



Weight: 1.7 g

Note 1: $C_M \le 500 \mu F$, $t_W \le 300 \mu s$, $V_D \le 350 V$

Note 2: di / dt Test condition

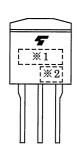
 V_{DRM} = 0.5 × Rated, $I_{TM} \le 25A$, $t_{gw} \ge 10\mu s$, $t_{gr} \le 250ns$, $i_{gp} = I_{GT} \times 2.0$

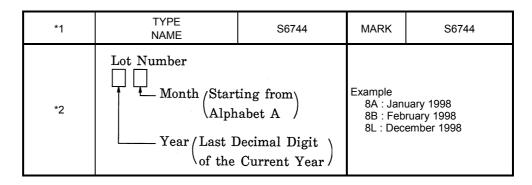


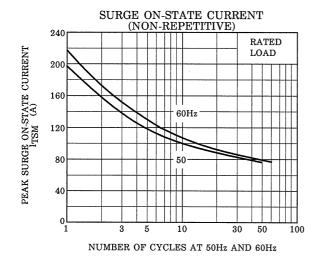
ELECTRICAL CHARACTERISTICS (Ta = 25°C)

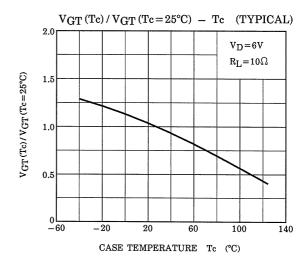
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
Repetitive Peak Off-State Current and Repetitive Peak Reverse Current	I _{DRM} I _{RRM}	V _{DRM} = V _{RRM} = Rated	_	_	10	μΑ
Peak On-State Voltage	V_{TM}	I _{TM} = 25A	_	_	1.5	V
Gate Trigger Voltage	V _{GT}	$V_{\rm D} = 6V, R_{\rm I} = 10\Omega$	_	_	1.0	V
Gate Trigger Current	I _{GT}	ν _D = ον, τι <u>c</u> = τοιχ	_	_	20	mA
Gate Non-Trigger Voltage	V_{GD}	V _D = Rated × 2 / 3, Tc = 125°C	0.2	_	_	V
Critical Rate of Rise of Off-State Voltage	dv / dt	V _{DRM} = Rated,Tc = 125°C, Exponential Rise	_	50	_	V / µs
Holding Current	lΗ	V _D = 6V, I _{TM} = 1A	_	_	40	mA
Latching Current	ΙL	$V_D = 6V, f = 50Hz,$ $t_{gw} = 100\mu s, i_G = 40mA$	_	_	60	mA
Thermal Resistance	R _{th (j−a)}	Junction to Ambient	_	_	70	°C/W

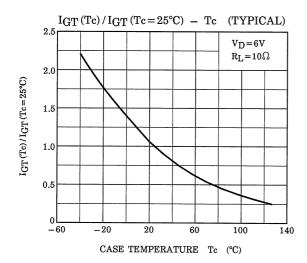
MARKING

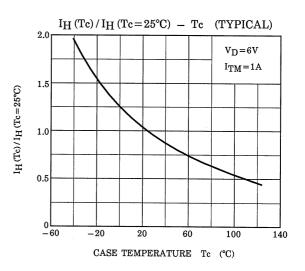












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